

**K. J. SOMAIYA COLLEGE OF ENGINEERING**  
**DEPARTMENT OF ELECTRONICS ENGINEERING**  
**ELECTRONIC CIRCUITS**  
**Differential Amplifier Circuits**

**Numerical 1**

Determine the following for the circuit given in figure 1. Assume  $\beta_1 = \beta_2 = 100$

- a) Name the circuit
- b)  $I_C$ ,  $I_B$
- c)  $V_{CE}$
- d) Differential voltage gain
- e) Common mode gain
- f) CMRR in dB

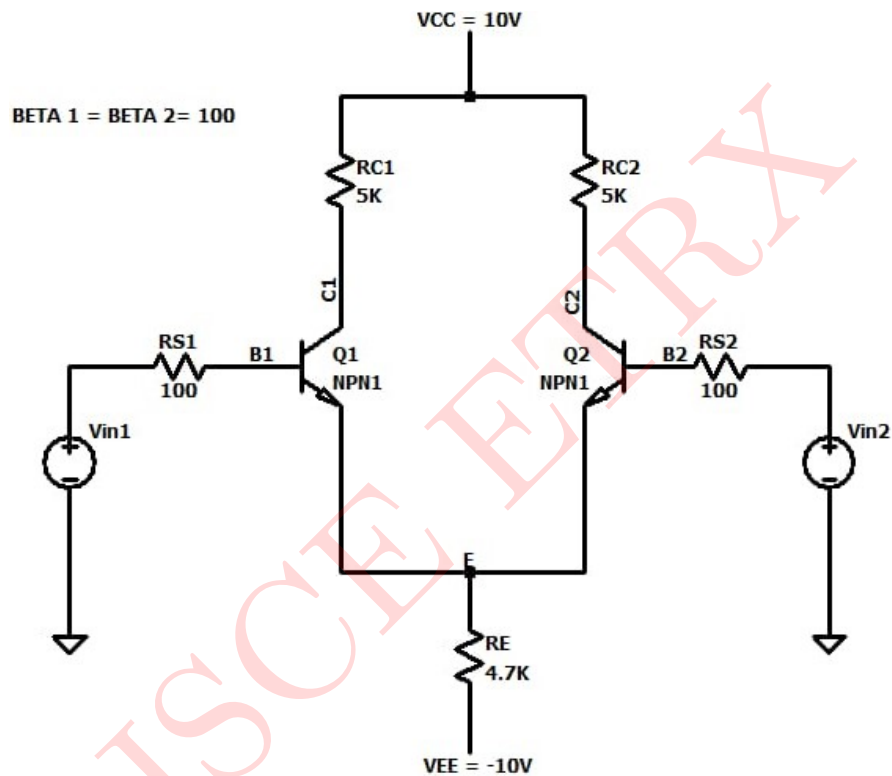


Figure 1: Circuit for Design 1

**Solution:**

**a) Name the circuit:**

The given above is dual input balanced output (DIBO)

**DC Analysis:**

b) Applying KVL to the first part we get,

$$V_{EE} - V_{BE} - (1 + \beta)I_B R_E = 0$$

$$I_B = \frac{V_{EE} - V_{BE}}{(1 + \beta)R_E}$$

$$I_B = \frac{10 - 0.7}{100 + (101)4.7k}$$

$$I_B = \frac{9.3}{100 + 101 \times 9.4k}$$

$$\mathbf{I_B = 9.79\mu A}$$

$$I_{CQ} = \beta I_{BQ}$$

$$I_{CQ} = 100 \times 9.79\mu A$$

$$\mathbf{I_{CQ} = 0.979mA}$$

$$I_{CQ_1} = I_{CQ_2} = 0.979mA$$

**c) Calculation of  $V_{CEQ}$  :**

$$V_{CEQ} = V_{CC} + V_{EE} - I_C(R_C + 2R_E)$$

$$V_{CEQ} = 10 + 10 - 0.97mA(5k + 9.4k)$$

$$V_{CEQ_1} = V_{CEQ_2} = 5.91V$$

$$\text{Q-Point} = (V_{CEQ_1}, I_{CQ_1}) = (V_{CEQ_2}, I_{CQ_2}) = (5.91V, 0.979mA)$$

**Find  $A_d$ ,  $A_{cm}$  and CMRR:**

d) Calculation of differential voltage gain  $A_d$

$$r_\pi = \frac{\beta \times V_T}{I_C} = \frac{100 \times 26mV}{0.979mA}$$

$$\mathbf{r_\pi = 2.655k\Omega}$$

$$|A_d| = \frac{\beta R_C}{R_S + r_\pi} = \frac{100 \times 5}{0 + 2.655k} \quad (\text{Since } R_S = 0)$$

$$|A_d| = \frac{500}{2.655k\Omega}$$

$$\mathbf{|A_d| = 188.31}$$

e) Calculation of common mode gain  $A_{cm}$ :

$$A_{cm} = \left| \frac{R_c}{2R_E} \right|$$

$$A_{cm} = \left| \frac{5k}{9.4k} \right|$$

$$\mathbf{A_{cm} = 0.532}$$

$$CMRR = \left| \frac{A_d}{A_{cm}} \right| = \left| \frac{188.32}{0.532} \right|$$

$$CMRR = 353.984$$

$$CMRR(dB) = 20 \log_{10} \left( \frac{A_d}{A_{cm}} \right) = 20 \log_{10}(353.984)$$

$$CMRR(dB) = 50.97dB$$

### SIMULATED RESULTS:

Above circuit is simulated in LTspice and results are as follows:

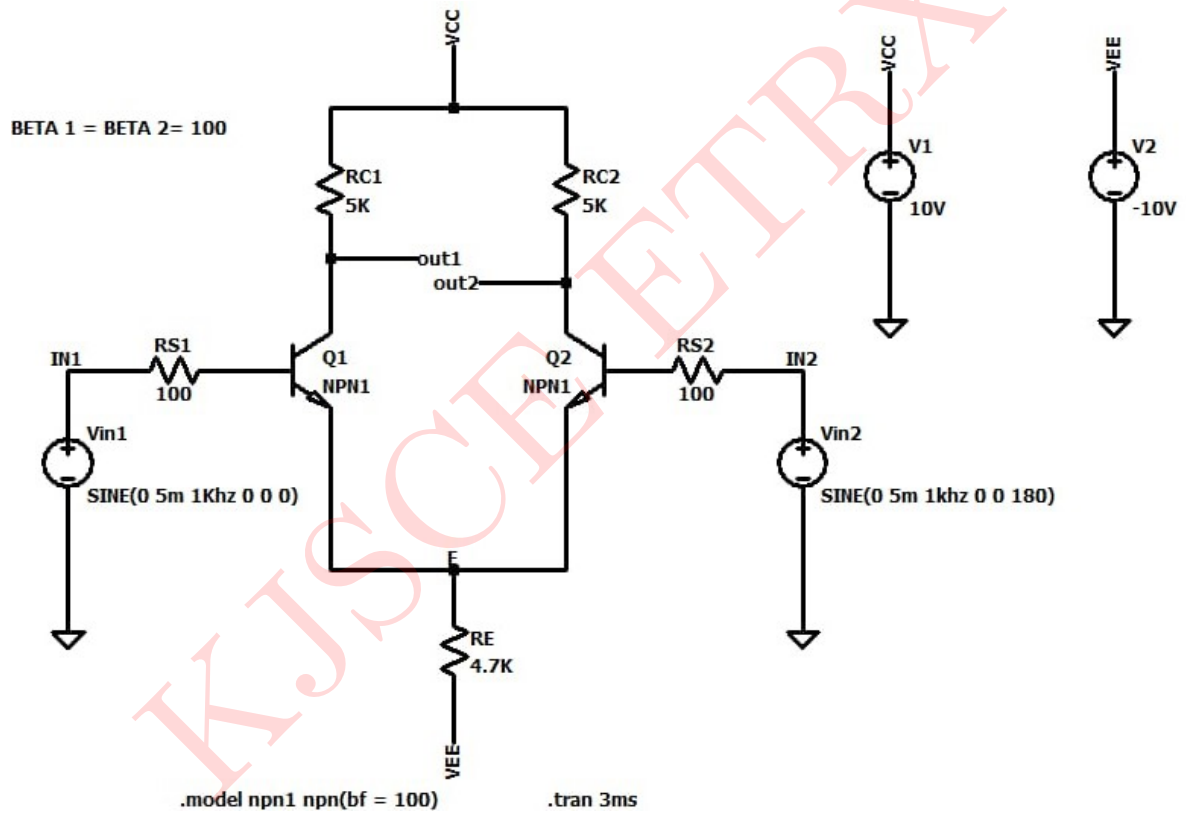


Figure 2: Circuit Schematic: Results

### Output Waveforms:

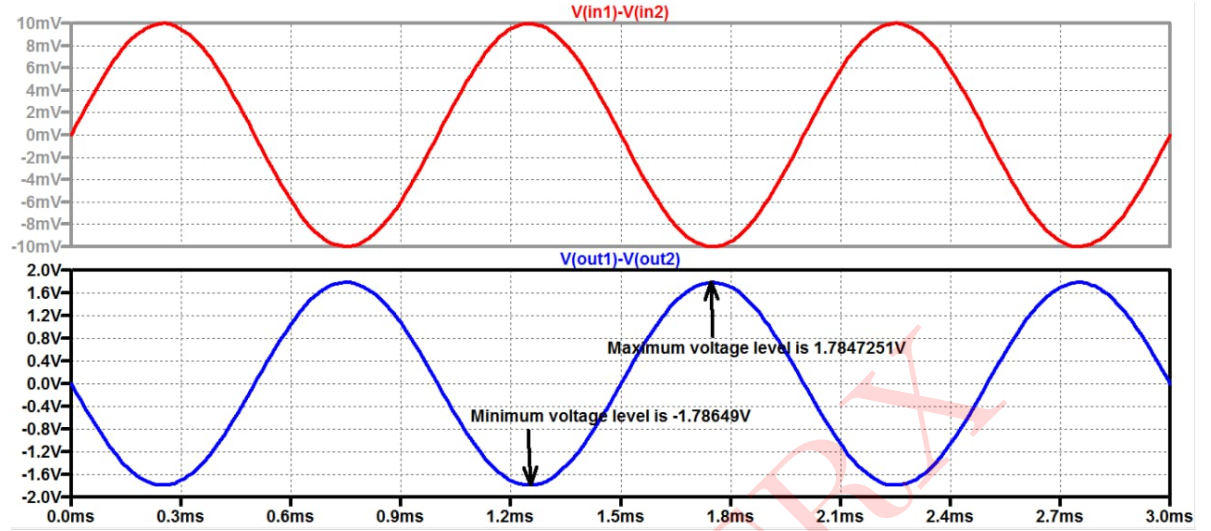


Figure 3: Input and Output waveforms

Comparison between theoretical and simulated values is given below:

Parameters	Theoretical Values	Simulated Values
$I_{C1}$	$0.979mA$	$0.971mA$
$I_{C2}$	$0.979mA$	$0.971mA$
$V_{CE1}$	$5.91V$	$5.93V$
$V_{CE2}$	$5.91V$	$5.93V$
$ A_d $	188.32	178.5
$A_{cm}$	0.532	—
CMRR(dB)	50.97	—

Table 1: Numerical 1

## Numerical 2

Determine the following for the circuit given in figure 4. The transistor parameters are  $k_{n1} = k_{n2} = 50\mu A/V^2$ ,  $\lambda_1 = \lambda_2 = 0.02V^{-1}$  and  $V_{TN1} = V_{TN2} = 1V$

- a)  $I_{D1}$ ,  $I_{D2}$
- b)  $V_{GS1}$ ,  $V_{GS2}$
- c) Differential voltage gain
- d) Common mode voltage gain
- e) CMRR in dB

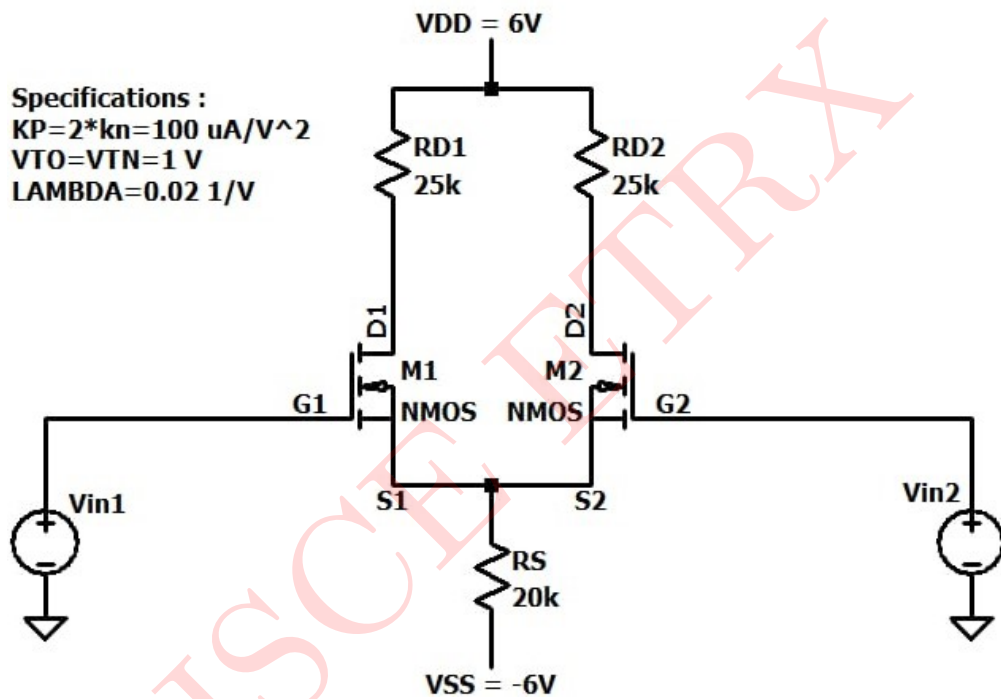


Figure 4: Circuit for Numerical 2

**Solution:**

**DC Analysis:**

$$V_{GS} = V_{SS} - 2I_D R_S$$

$$V_{GS} = 6 - 2I_D R_S \quad \text{.....(1)}$$

$$\text{Given, } k_{n1} = k_{n2} = 50\mu A/V^2$$

The given circuit is a dual input unbalanced output (DIUO) differential amplifier. For DC analysis, consider only one transistor as both transistors are identical.

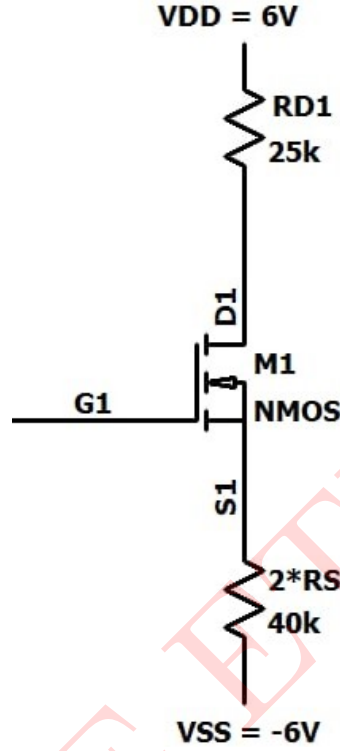


Figure 5: GS loop of MOSFET

Applying KVL to G-S loop we get,

$$-V_{GS_1} - 2I_{D_1}R_S - V_{SS} = 0$$

$$V_{GS_1} = -V_{SS} - 2I_{D_1}R_S$$

$$V_{GS_1} = 6 - 2I_{D_1}20k$$

$$V_{GS_1} = 6 - I_{D_1}40k$$

Applying KVL to D-S loop we get,

$$V_{DD} - I_{D_1}R_{D_1} - V_{DS_1} - I_{D_1}2R_S - V_{SS} = 0$$

$$V_{DS_1} = V_{DD} - I_{D_1}R_{D_1} - I_{D_1}2R_S - V_{SS} = 0$$

$$V_{DS_1} = 6 - I_{D_1}25k - I_{D_1}40k + 6$$

$$V_{DS_1} = 12 - I_{D_1}65k$$

.....(2)

From current equation we get,

$$I_{D_1} = k_n(V_{GS_1} - V_{TN_1})^2(1 + \lambda V_{DS_1})$$

$$I_{D_1} = 50 \times 10^{-6}(6 - I_{D_1}40k - 1)^2(1 + 0.02(12 - I_{D_1}65k))$$

$$I_{D_1} = 50 \times 10^{-6}(5 - I_{D_1}40k)^2(1 + 0.24 - I_{D_1}1.3k)$$

$$I_{D_1} = 50 \times 10^{-6}(5 - I_{D_1}40k)^2(1.24 - I_{D_1}1.3k)$$

$$I_{D_1} = 50 \times 10^{-6} (36 + I_{D_1}^2 1600 \times 10^6 - I_{D_1} 400 \times 10^3) (1.24 - I_{D_1} 1.3k)$$

$$I_{D_1} = 50 \times 10^{-6} (31 + 19844 I_{D_1}^2 \times 10^6 - 496 I_{D_1} \times 10^3 - 32.5 I_{D_1} \times 10^3 - 2.080 I_{D_1}^3 \times 10^9 + 520 I_{D_1}^2 \times 10^6)$$

$$I_{D_1} = 50 \times 10^{-6} (31 - 528.5 I_{D_1} \times 10^3 + 2504 \times 10^6 I_{D_1}^2 - 2080 I_{D_1}^3 \times 10^9)$$

$$I_{D_1} = 1.55 \times 10^{-4} - 26.42 I_{D_1} + 125.200 I_{D_1}^2 - 104 \times 10^6 I_{D_1}^3$$

$$104 \times 10^6 I_{D_1}^3 - 125.200 I_{D_1}^2 + 27.42 I_{D_1} - 1.55 \times 10^{-4} = 0$$

Solving the above cubic equation we get,

$$I_{D_1} = 9.4 \times 10^{-4} \text{ or } I_{D_1} = 1.7 \times 10^{-4} \text{ or } I_{D_1} = 9.28 \times 10^{-5}$$

Now let,  $I_{D_1} = 9.28 \times 10^{-5} A$

$$V_{GS} = 6 - I_D 40k \quad (\text{From (1)})$$

$$V_{GS} = 6 - 9.28 \times 10^{-5} \times 40 \times 10^3$$

$$V_{GS} = 2.288V$$

$V_{GS}$  must be greater than  $V_{TN_1}$

$$\mathbf{V_{GS} = 2.288V}$$

$$I_{D_1} = 9.28 \times 10^{-5} A$$

$$\mathbf{I_{D_1} = 0.0928mA}$$

From eq(2) we get,

$$V_{DS_1} = 12 - I_{D_1} 65k$$

$$V_{DS_1} = 12 - 0.0928 \times 10^{-3} 65 \times 10^3$$

$$\mathbf{V_{DS_1} = 5.968V}$$

$$\text{Now, } V_{D_1} = V_{DD} - I_{D_1} R_{D_1}$$

$$V_{D_1} = 6 - 0.0928 \times 10^{-3} \times 25 \times 10^3$$

$$\mathbf{V_{D_1} = 3.68V}$$

As both the transistors are equal,

$$I_{D_1} = I_{D_2} = 0.0928mA$$

$$V_{DS_1} = V_{DS_2} = 5.968V$$

$$V_{D_1} = V_{D_2} = 3.68V$$

$$\text{And } I_S = 2I_{D_1}$$

$$I_S = 2 \times 0.0928 \times 10^{-3}$$

$$\mathbf{I_S = 0.1964mA}$$

### AC Analysis:

$$g_{m1} = 2k_n(V_{GS1} - V_{TN1})(1 + \lambda V_{DS1})$$

$$g_{m1} = 2 \times 0 \times 10^{-6} (2.288 - 1)(1 + 0.02 \times 5.968)$$

$$g_{m1} = (100 \times 1.288)(1.119)$$

$$\mathbf{g_{m1} = 0.144mA/V}$$

$$r_{d1} = \frac{1}{\lambda I_{D1}} = \frac{1}{0.02 \times 0.0928 \times 10^{-3}}$$

$$\mathbf{r_{d1} = 538.79k\Omega}$$

As both transistors are identical,

$$g_{m1} = g_{m2} = 0.144$$

$$r_{d1} = r_{d2} = 538.79k\Omega$$

**Calculation of differential voltage gain  $A_d$ :**

$$|A_d| = \frac{g_m(r_d \parallel R_D)}{2}$$

$$|A_d| = \frac{0.144(538.79k \parallel 25k)}{2}$$

$$\mathbf{|A_d| = 1.72}$$

**Calculation of common mode gain  $A_{cm}$ :**

$$|A_{cm}| = \frac{g_m(r_d \parallel R_D)}{1 + 2g_m R_S}$$

$$|A_{cm}| = \frac{0.144(538.79k \parallel 25k)}{1 + 2 \times 0.144 \times 20k}$$

$$\mathbf{|A_{cm}| = 0.597}$$

$$\text{CMRR} = \left| \frac{A_d}{A_{cm}} \right| = \left| \frac{1.72}{0.597} \right|$$

$$\mathbf{\text{CMRR} = 2.88}$$

$$\text{CMRR(dB)} = 20 \log_{10} \left( \frac{A_d}{A_{cm}} \right) = 20 \log_{10}(2.88)$$

$$\mathbf{\text{CMRR(dB)} = 9.18dB}$$



## SIMULATED RESULTS:

Above circuit is simulated in LTspice and results are as follows:

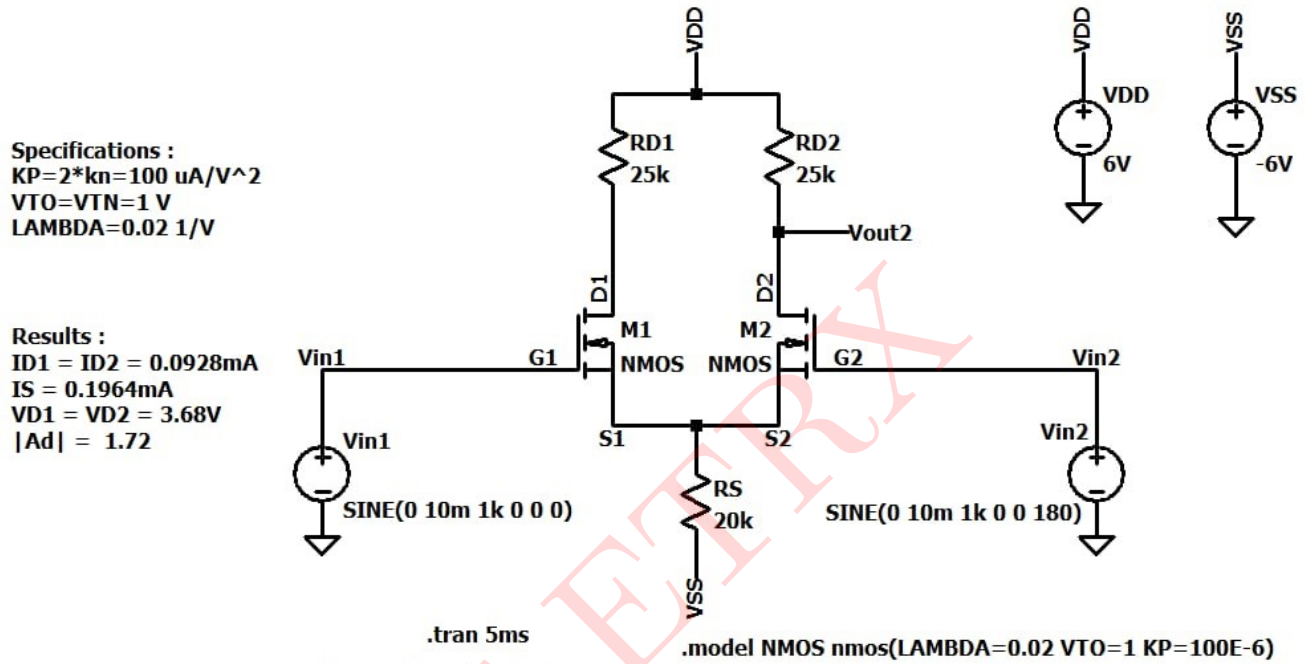


Figure 6: Circuit Schematic: Results

## Output Waveforms:

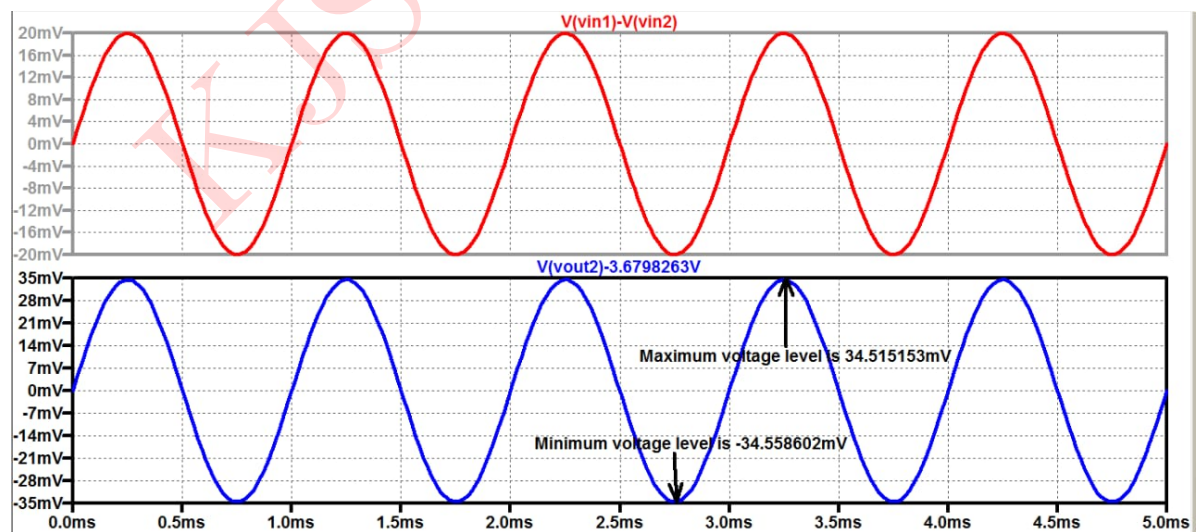


Figure 7: Input and Output waveforms

Comparison between theoretical and simulated values is given below:

Parameters	Theoretical Values	Simulated Values
$I_S$	$0.1964mA$	$0.092mA$
$I_{D_1} = I_{D_2}$	$0.0928mA$	$0.0928mA$
$V_{DS_1} = V_{DS_2}$	$5.968V$	$5.95V$
$V_{D_1} = V_{D_2}$	$3.68V$	$3.67V$
Differential voltage gain( $A_d$ )	$1.72$	$1.72$
Common mode voltage gain( $A_{cm}$ )	$0.597$	—
CMRR(dB)	$9.18dB$	—

Table 2: Numerical 2

### Numerical 3

Determine the following for the circuit given in figure 8. The transistor parameters are  $I_{DSS} = 12mA$ ,  $V_P = -2.5V$

a)  $I_{D1}$ ,  $I_{D2}$

b) DC values of  $V_{o1}$ ,  $V_{o2}$

c) Single ended output gain  $\frac{V_{o1}}{V_1 - V_2}$

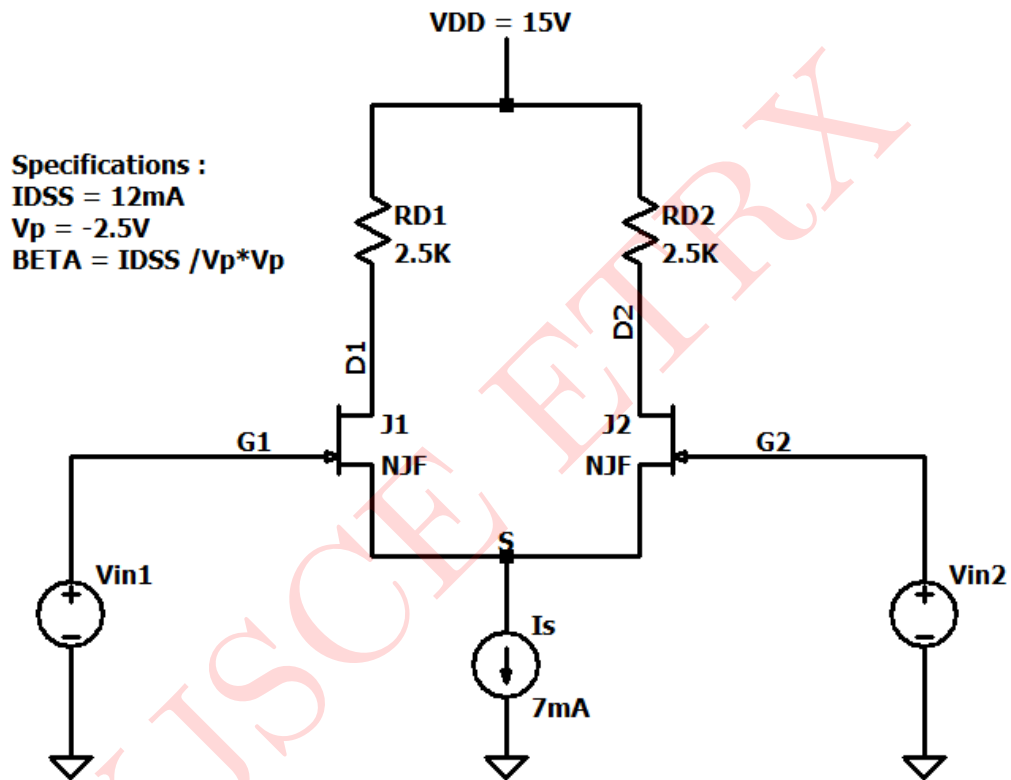


Figure 8: Circuit for Numerical 3

**Solution:**

#### DC Analysis:

Above circuit is a differential amplifier using JFET

$$1) I_{D1} = I_{D2} = \frac{7mA}{2}$$

$$I_{D1} = I_{D2} = 3.5mA$$

$$2) \text{ DC value of } V_{o1} = V_{o2} = V_{DD} - I_D R_D$$

$$V_{o1} = V_{o2} = 15 - 3.5mA \times 2.5k$$

$$V_{o1} = V_{o2} = 6.25V$$

3)  $\frac{V_{o1}}{V_1 - V_2}$ , means output is taken from drain  $D_1$  of transistor

Assuming  $V_{o2} > V_{o1}$ ; DIUO

$$A_d = \left( \frac{V_{o1}}{V_1 - V_2} \right) = \frac{-g_m R_D}{2}$$

$$\text{For JFET, } I_D = I_{DSS} \left( 1 - \frac{V_{GS}}{V_P} \right)^2$$

$$\text{i.e. } \frac{I_D}{I_{DSS}} = \left( 1 - \frac{V_{GS}}{V_P} \right)^2$$

$$\text{i.e. } \left( 1 - \frac{V_{GS}}{V_P} \right) = \sqrt{\frac{I_D}{I_{DSS}}}$$

$$g_m = \frac{2I_{DSS}}{|V_P|} \left( 1 - \frac{V_{GS}}{V_P} \right)$$

$$g_m = \frac{2I_{DSS}}{|V_P|} \sqrt{\frac{I_D}{I_{DSS}}}$$

$$g_m = \frac{2 \times 12mA}{2.5V} \sqrt{\frac{3.5mA}{12mA}}$$

$$\mathbf{g_m = 5.08mA/V}$$

$$A_d = \frac{V_{o1}}{V_1 - V_2} = -\frac{g_m R_D}{2} = \frac{-5.08 \times 10^{-3} \times 2.5k}{2}$$

$$|\mathbf{A_d}| = \frac{\mathbf{V_{o1}}}{\mathbf{V_1 - V_2}} = \mathbf{6.35}$$

## SIMULATED RESULTS:

Above circuit is simulated in LTspice and results are as follows:

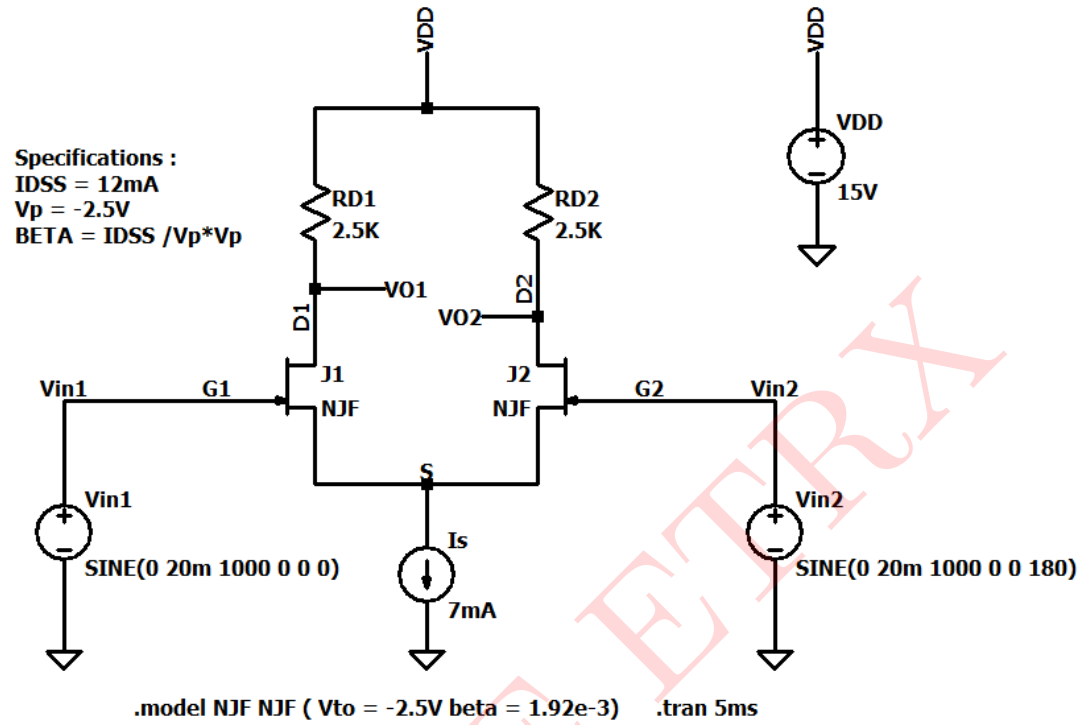


Figure 9: Circuit Schematic: Results

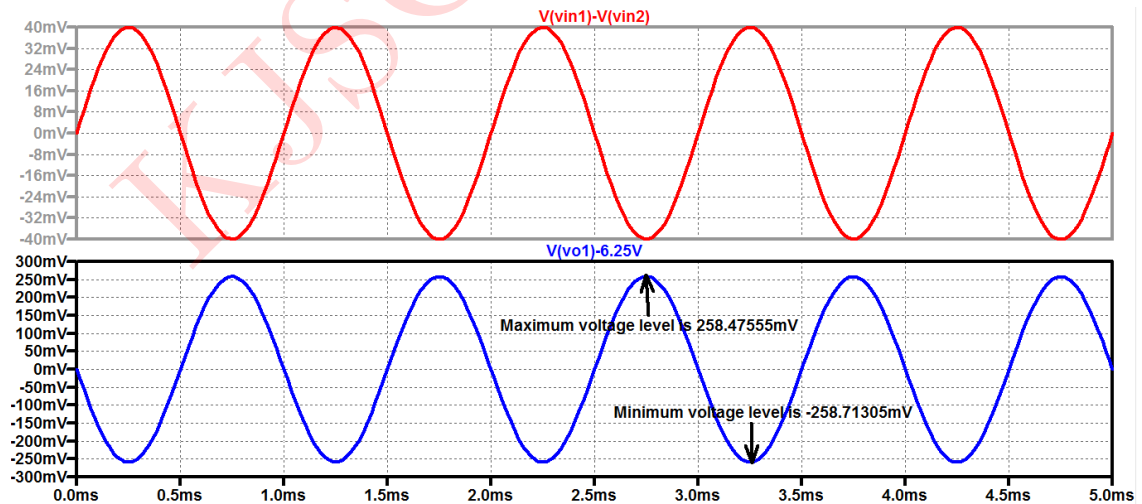


Figure 10: Input and Output waveforms

Comparison between theoretical and simulated values is given below:

Parameters	Theoretical Values	Simulated Values
$I_{D_1} = I_{D_2}$	$3.5mA$	$3.5mA$
$V_{D_1} = V_{D_2}$	$6.25V$	$6.25V$
Differential voltage gain $ A_d $	6.35	6.46

Table 3: Numerical 3

\*\*\*\*\*

KJSCE ETRX